

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic Drain-Source Voltage Gate-Source Voltage			Symbol	Value	Units V V	
			V _{DSS}	30		
			V _{GSS}	±25		
Continuous Drain Current (Note 6) V _{GS} = 10V	Steady State	T _A = +25°C T _A = +70°C	ID	7.3 5.7	A	
	t<10s	T _A = +25°C T _A = +70°C	ID	9.7 7.8	A	
Continuous Drain Current (Note 6) V _{GS} = 4.5V	Steady State	T _A = +25°C T _A = +70°C	ID	5.5 4.3	A	
	t<10s	T _A = +25°C T _A = +70°C	ID	7.6 5.8	A	
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I _{DM}	60	A	
Maximum Body Diode continuous Current			ls	2.5	А	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

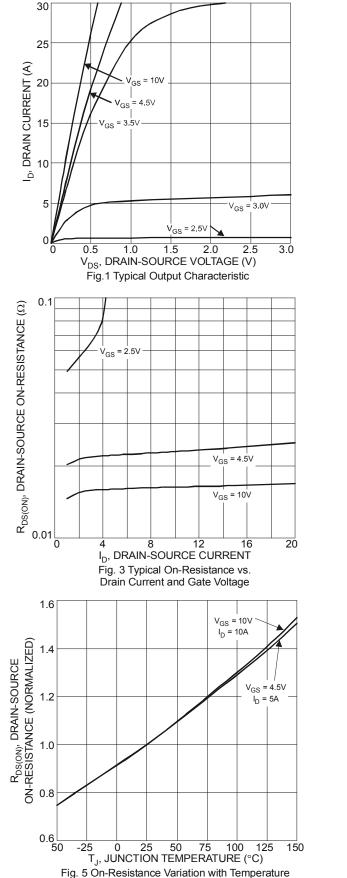
Characteristic		Symbol	Value	Units
Tatal Dawar Dissinction (Nata 5)	T _A = +25°C	D	1.4	W
Total Power Dissipation (Note 5)	T _A = +70°C	PD	0.9	
Thermal Resistance, Junction to Ambient (Note 5)	Steady state	P	90	°C/W
	t<10s	$R_{ extsf{ heta}JA}$	50	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	Р	1.7	W
	T _A = +70°C	PD	1.1	
Thermal Desistance Junction to Ambient (Note 6)	Steady state	P	75	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{ extsf{ heta}JA}$	42	°C/W
Thermal Resistance, Junction to Case (Note 6)		$R_{\theta JC}$	7.6	°C/W
Operating and Storage Temperature Range		T _{J.} T _{STG}	-55 to +150	°C

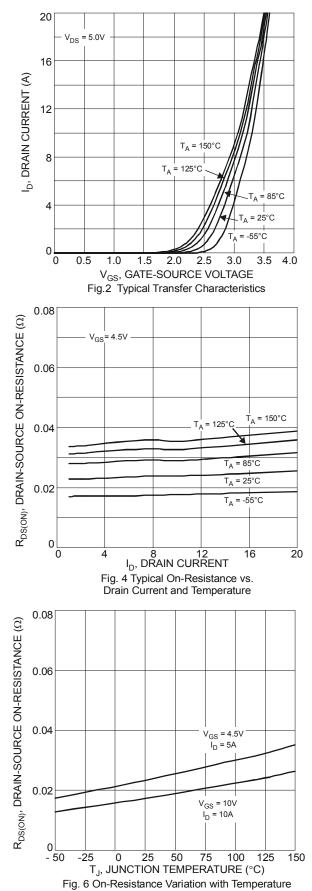
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	0,			max	•		
Drain-Source Breakdown Voltage	BV _{DSS}	30	-	-	V	V _{GS} = 0V, I _D = 250µA	
Zero Gate Voltage Drain Current	I _{DSS}	-	-	1	μA	$V_{DS} = 24V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	-	-	±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(th)}	1	1.7	2.1	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance		-	15	21	mΩ	V _{GS} = 10V, I _D = 10A	
	R _{DS} (ON)	-	20	35		V _{GS} = 4.5V, I _D = 8.5A	
Forward Transfer Admittance	Y _{fs}	-	8.3	-	S	V _{DS} = 5V, I _D = 6.9A	
Diode Forward Voltage	V _{SD}	0.5	-	1.2	V	V _{GS} = 0V, I _S = 1A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	-	697	-	pF		
Output Capacitance	Coss	-	97	-	pF	V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	-	67	-	pF		
Gate resistance	Rg	-	1.47	-	Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1.0MHz	
Total Gate Charge (V _{GS} = 4.5V)	Qg	-	6.0	-	nC		
Total Gate Charge (V _{GS} = 10V)	Qg	-	13.2	-	nC	V _{GS} = 10V, V _{DS} = 15V,	
Gate-Source Charge	Q _{gs}	-	2.2	-	nC	I _D = 9A	
Gate-Drain Charge	Q _{gd}	-	1.8	-	nC	-	
Turn-On Delay Time	t _{D(on)}	-	4.3	-	ns		
Turn-On Rise Time	tr	-	4.4	-	ns	V _{DD} = 15V, V _{GS} = 10V,	
Turn-Off Delay Time	t _{D(off)}	-	20.1	-	ns	$R_{L} = 15\Omega, I_{D} = 1A, R_{G} = 6\Omega$	
Turn-Off Fall Time	t _f	-	4.1	-	ns	1	
Reverse Recovery Time	T _{rr}	-	7.3	-	ns		
Reverse Recovery Charge	Q _{rr}	-	7.9	-	nC	I _F = 9A, di/dt = 500A/μs	

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing. Notes:

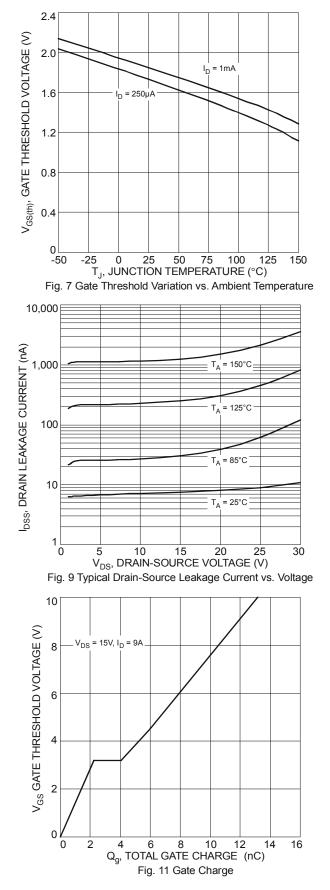


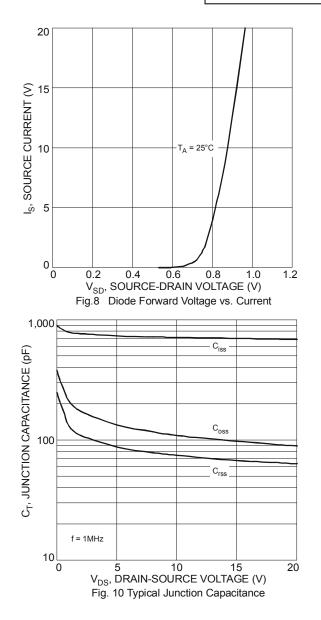




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Max

1.75

0.20

1.50

0.25

0.5

4.95

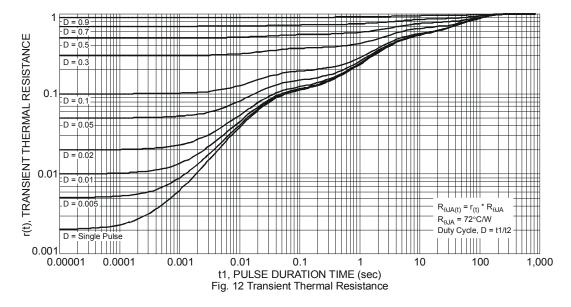
6.10

3.95

0.35

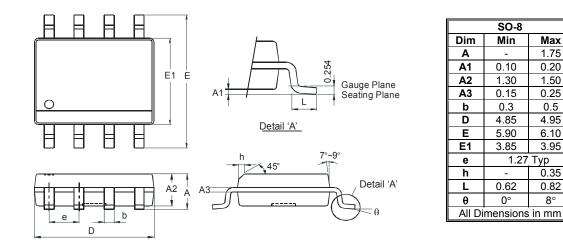
0.82

8°



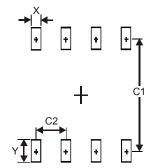
Package Outline Dimensions

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Suggested Pad Layout

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Dimensions	Value (in mm)
Х	0.60
Y	1.55
C1	5.4
C2	1.27

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